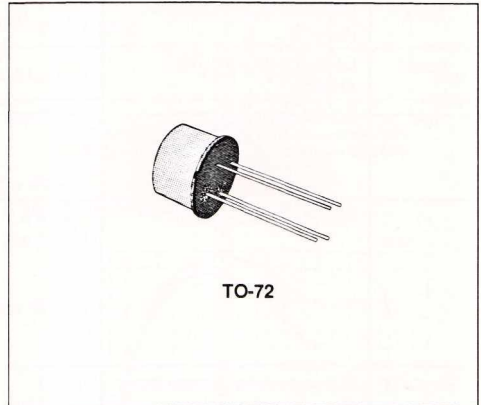


## WIDE BAND VHF/UHF AMPLIFIER

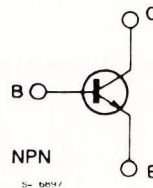
- SILICON PLANAR EPITAXIAL TRANSISTORS
- TO-72 METAL CASE
- VERY LOW NOISE

### APPLICATIONS :

- TELECOMMUNICATIONS
- WIDE BAND UHF AMPLIFIER
- RADIO COMMUNICATIONS



### INTERNAL SCHEMATIC DIAGRAM



### DESCRIPTION

The BFX89 and BFY90 are silicon planar epitaxial NPN transistors produced using interdigitated base emitter geometry. They are particularly designed for use in wide band common-emitter linear amplifiers up to 1 GHz. They feature very high  $f_T$ , low reverse capacitance, excellent cross modulation properties and very low noise performance. The BFY90 is complementary to the BFR99A. Typical applications include telecommunication and radio communication equipment.

### ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
$V_{CBO}$	Collector-base Voltage ( $I_E = 0$ )	30	V
$V_{CER}$	Collector-emitter Voltage ( $R_{BE} \leq 50 \Omega$ )	30	V
$V_{CEO}$	Collector-emitter Voltage ( $I_B = 0$ )	15	V
$V_{EBO}$	Emitter-base Voltage ( $I_C = 0$ )	2.5	V
$I_C$	Collector Current	25	mA
$I_{CM}$	Collector Peak Current ( $f \geq 1$ MHz)	50	mA
$P_{tot}$	Total Power Dissipation at $T_{amb} \leq 25^\circ C$	200	mW
$T_{stg}, T_j$	Storage and Junction Temperature	- 65 to 200	$^\circ C$

**THERMAL DATA**

$R_{th\ j-case}$	Thermal Resistance Junction-case	Max	580	$^{\circ}C/W$
$R_{th\ j-amb}$	Thermal Resistance Junction-ambient	Max	880	$^{\circ}C/W$

**ELECTRICAL CHARACTERISTICS** ( $T_{amb} = 25\ ^{\circ}C$  unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
$I_{CBO}$	Collector Cutoff Current ( $I_E = 0$ )	$V_{CB} = 15\ V$			10	nA
$V_{CEK}^*$	Collector-emitter Knee Voltage	$I_C = 20\ mA$			0.75	V
$h_{FE}$	DC Current Gain	$I_C = 2\ mA$ $V_{CE} = 1\ V$ for <b>BFX89</b> for <b>BFY90</b>  $I_C = 25\ mA$ $V_{CE} = 1\ V$	20 25 20		150 150 125	
$f_T$	Transition Frequency	$V_{CE} = 5\ V$ $f = 500\ MHz$ $I_C = 2\ mA$  $I_C = 25\ mA$  for <b>BFX89</b> for <b>BFY90</b>  for <b>BFX89</b> for <b>BFY90</b>		1 1.1 1.2 1.4		GHz GHz GHz GHz
$C_{CBO}^{(1)}$	Collector-base Capacitance	$I_E = 0$ $V_{CB} = 10\ V$ $f = 1\ MHz$ for <b>BFX89</b> for <b>BFY90</b>			1.7 1.5	pF pF
$C_{re}^{(2)}$	Reverse Capacitance	$I_C = 2\ mA$ $V_{CE} = 5\ V$ $f = 1\ MHz$ for <b>BFX89</b> for <b>BFY90</b>		0.6 0.6	0.8	pF pF
$NF^{(2)}$	Noise Figure	$I_C = 2\ mA$ $V_{CE} = 5\ V$ $R_g = \text{Optimized}$ $f = 100\ kHz$ for <b>BFY90</b> Only $f = 200\ MHz$ $R_g = \text{Optimized}$ for <b>BFX89</b> for <b>BFY90</b> $f = 500\ MHz$ $R_g = 50\ \Omega$ for <b>BFX89</b> for <b>BFY90</b> $f = 800\ MHz$ $R_g = \text{Optimized}$ for <b>BFX89</b> for <b>BFY90</b>			4 4 3.5 5 7 5.5	dB dB dB dB dB dB
$G_{pe}^{(2)}$	Power Gain (not neutralized)	for <b>BFX89</b> $I_C = 8\ mA$ $V_{CE} = 10\ V$ $f = 200\ MHz$ $f = 800\ MHz$  for <b>BFY90</b> $I_C = 14\ mA$ $V_{CE} = 10\ V$ $f = 200\ MHz$ $f = 800\ MHz$	19  21	22 7 23 8		dB dB dB dB

\*  $I_B$  = value for which  $I_C = 22\ mA$  at  $V_{CE} = 1\ V$

(1) Shield lead not grounded

(2) Shield lead grounded

(3)  $f_p = 202\ MHz$ ,  $f_g = 205\ MHz$ ,  $f_{2Q-p} = 208\ MHz$

(4)  $f_p = 798\ MHz$ ,  $f_g = 802\ MHz$ ,  $f_{2Q-p} = 806\ MHz$

**ELECTRICAL CHARACTERISTICS** (continued)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
$P_o$	Output Power	for <b>BFX89</b> $I_C = 8 \text{ mA}$ $d_m = -30 \text{ dB}$ (3) Channel 9 (4) Channel 62 $V_{CE} = 10 \text{ V}$		6		mW
		for <b>BFY90</b> $I_C = 14 \text{ mA}$ $d_m = -30 \text{ dB}$ (3) Channel 9 (4) Channel 62 $V_{CE} = 10 \text{ V}$	10	12	mW	

\*  $I_B$  = value for which  $I_C = 22 \text{ mA}$  at  $V_{CE} = 1 \text{ V}$

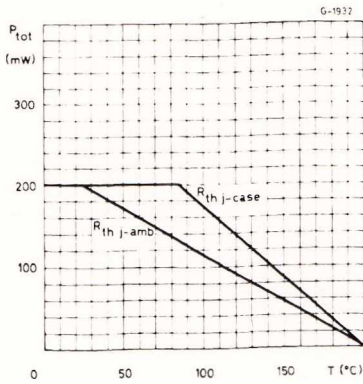
(1) Shield lead not grounded

(2) Shield lead grounded

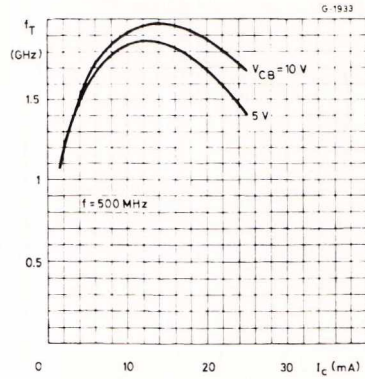
(3)  $f_o = 202 \text{ MHz}$ ,  $f_a = 205 \text{ MHz}$ ,  $f_{2dBI} = 208 \text{ MHz}$

(4)  $f_o = 798 \text{ MHz}$ ,  $f_a = 802 \text{ MHz}$ ,  $f_{2dBI} = 806 \text{ MHz}$

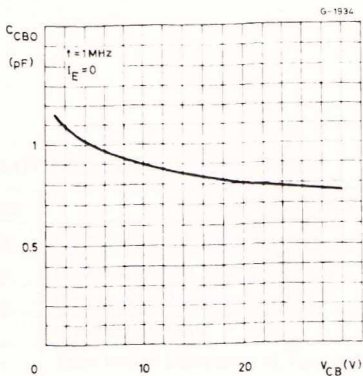
**Power Rating Chart.**



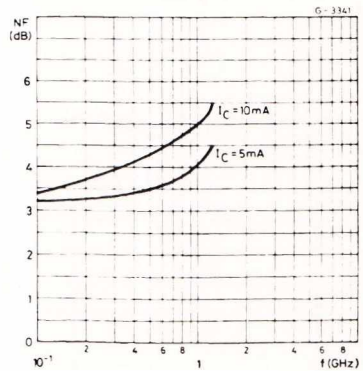
**Transition Frequency.**



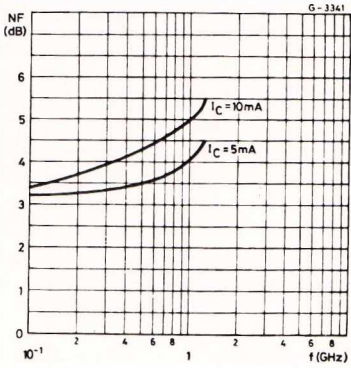
**Collector-base Capacitance.**



**Noise Figure vs. Collector Current.**



Noise Figure vs. Frequency.



Forward Transmission Gain vs. Frequency.

